SP6038 High Performance Synchronous Rectifying Converter

DESCRIPTION

SP6038 is a high performance and tightly integrated secondary side synchronous rectifier for switching mode power supply system. It combines a much lower voltage drop N-channel MOSFET emulate the traditional diode rectifier at the side of Flyback secondary converter, fundamental of SP6038 synchronous rectifier (SR) driver IC is based on our U.S. patented methods that utilize the principle of "prediction" logic circuit. The IC deliberates previous cycle timing SR in present cycle by control the "predictive" algorithm that makes adjustments to the turn-off time, in order to achieve maximum efficiency and avoid cross-conduction at the same time. The SP6038 is capable to adapt in almost all existing converters Resonance adjustments considered necessary.

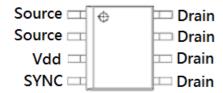
FEATURES

- Offers efficiency improvement over Schottky Diode (depends on drive configuration of the SR).
- Low Standby Power to meet DOE Lot 6 requirement.
- Secondary-side synchronous rectifier optimized for output system.
- Build-in 100V SR MOSFET with low Rdson
- Operating frequency up to 300 KHz.
- Synchronize to transformer secondary voltage waveform.
- Internal over voltage protection

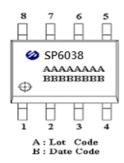
APPLICATIONS

- Switching Mode Power Supply (CCM&DCM&QR)
- Storage area network power supplies
- Telecommunication converters
- Embedded systems
- Industrial & commercial systems using high current processors
- Power converters to meet Lot 6 requirement

PIN CONFIGURATION (SOP-8)

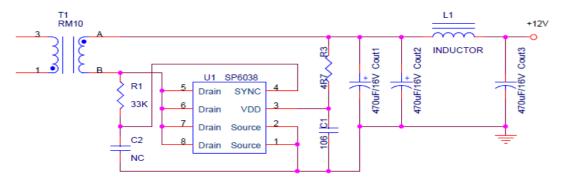


PART MARKING

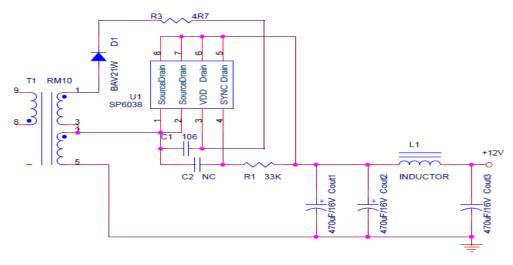


TYPICAL APPLCATION CIRCUIT

SP6038_application circuit_L/S



SP6038_application circuit_H/S with AUX winding



PIN DESCRIPTION

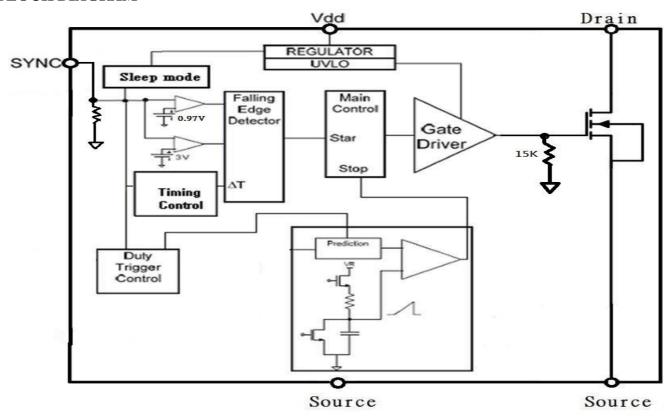
Pin	Symbol	Description
1	Source	Internal MOSFET Source
2	Source	Internal MOSFET Source
3	Vdd	DC supply voltage.
4	SYNC	Synchronized signal from Vds of SR MOSFET
5	Drain	Internal MOSFET drain
6	Drain	Internal MOSFET drain
7	Drain	Internal MOSFET drain
8	Drain	Internal MOSFET drain

ORDERING INFORMATION

Part Number	Package	Part Marking
SP6038S8RGB	SOP-8	SP6038

SP6038S8RGB : Tape Reel ; Pb – Free ; Halogen - Free

BLOCK DIAGRAM



ABSOULTE MAXIMUM RATINGS (TA=25°C, unless otherwise specified.)

The following ratings designate persistent limits beyond which damage to the device may occur.

Symbol	Parameter	Value	
V_{dd}	DC Supply Voltage	16	V
Vd to Vs	Drain to Source	100	V
P_D	Power Dissipation @ T _A =85°C (*)	0.3	W
TJ	Operating Junction Temperature Range	-40 to 125	$^{\circ}\mathbb{C}$
T_{STG}	Storage Temperature Range	-40 to 150	$^{\circ}\mathbb{C}$
T_{LEAD}	Lead Soldering Temperature for 5 sec.	260	$^{\circ}\mathbb{C}$

THERMAL RESISTANCE

Symbol	Parameter	Value	Unit	
RөJA	Thermal Resistance-Junction to Ambient (*)	110	°C/W	

^(*) The power dissipation and thermal resistance are evaluated under copper board mounted with free air conditions.



ELECTRICAL CHARACTERISTICS

 $(T_A=25^{\circ}\text{C}, V_{dd}=5\text{V}, Freq. =50 \text{ KHz}, Duty Cycle=50\%, unless otherwise specified.})$

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
SUPPLY INPUT						
Idd	Supply current	No load & Sleep mode		0.2	0.35	mA
Idd	Supply current	V _{SYNC} =Vdd ,No load	2.0	3.0	4.0	mA
Vdd	Supply voltage	Idd peak < 1A	4.3		16	V
Vdd on	Enable voltage		3.35	3.7	4.1	V
Vdd hysteresis	Enable voltage			0.2		V
Vovp	Over voltage protection		17	17.5	18.5	V
V _{OVP} hysteresis	Enable voltage			0.67		V
SYNC REFEREN	NCE (SYNC)	•			•	
Vshth	SYNC high threshold			3.0		V
Vslth	SYNC low threshold			0.9		V
Vsync	SYNC clamp voltage	Isync=3mA	Vdd+1.5			V
Vsync WK	SYNC wake-up voltage	Pulse width >1uS for Vdd=5V	6			V
Isync	SYNC input current				3	mA
Dynamic Protect						
Dt	Dynamic variable			5.1		uS
Ton-min	MOSG-C on time	PWM adjusts time > Dt	0.4		0.7	uS
SR MOSFET SE	CTION					
BVdss	MOSFET Drain-Source Breakdown Voltage	VGS=0V,ID=250uA	100			V
Rds(on)	Drain-Source On-Resistance	Vgs=10V,Id=20A		6.5	8.0	mΩ
Ciss	Input Capacitance			1876		
Coss	Output Capacitance	Vds=50V,Vgs=0V, f=1MHz		348		pF
Crss	Reverse Transfer Capacitance			5.6		
Td(on)	Turn On Time	VDD=50V,ID=14A,VGS=10V		7		
Td(off)	Turn Off Time	$R_{G}=6\Omega$		20		nS

Information provided is alleged to be exact and consistent. SYNC Power Corporation presumes no responsibility for the penalties of use of such information or for any violation of patents or other rights of third parties, which may result from its use. No license is granted by allegation or otherwise under any patent or patent rights of SYNC Power Corporation. Conditions mentioned in this publication are subject to change without notice. This publication surpasses and replaces all information previously supplied. SYNC Power Corporation products are not authorized for use as critical components in life support devices or systems without express written approval of SYNC Power Corporation.

© The SYNC Power logo is a registered trademark of SYNC Power Corporation
© 2020 SYNC Power Corporation – Printed in Taiwan – All Rights Reserved
SYNC Power Corporation
7F-2, No.3-1, Park Street
NanKang District (NKSP), Taipei, Taiwan, 115, R.O.C
Phone: 886-2-2655-8178
Fax: 886-2-2655-8468

http://www.syncpower.com